DATA SHEET

74ALVC16244/74ALVCH16244

2.5V/3.3V 16-bit buffer/line driver (3-State)

Product specification
Supersedes data of 1997 Mar 21
IC24 Data Handbook

1998 Jun 29

Philips
Semiconductors

PHILIPS

16-bit buffer/line driver (3-State)

74ALVC16244/ 74ALVCH16244

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTE™ flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Bus hold on data inputs (74ALVCH16244 only)
- Output drive capability 50Ω transmission lines @ 85°C
- Current drive ±24 mA at 3.0 V

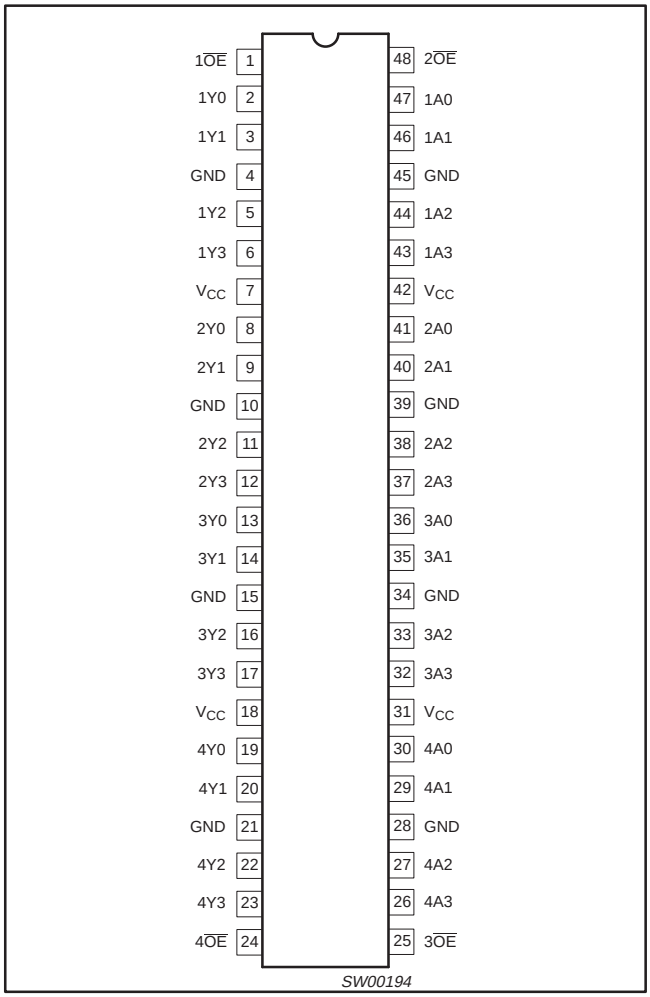
DESCRIPTION

The 74ALVC16244(74ALVCH16244) is a 16-bit non-inverting buffer/line driver with 3-State outputs. The device can be used as four 4-bit buffers, two 8-bit buffers or one 16-bit buffer. The 3-State outputs are controlled by the output enable inputs $1\overline{OE}$ and $2\overline{OE}$. A HIGH on $n\overline{OE}$ causes the outputs to assume a high impedance OFF-state.

The 74ALVCH16244 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

The 74ALVC16244 has 5V tolerant inputs.

PIN CONFIGURATION



QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25°C; $t_r = t_f \leq 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS		TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay An to Yn	V_{CC} = 2.5V, CL = 30pF V_{CC} = 3.3V, CL = 50pF		1.9 1.9	ns
C_I	Input capacitance			5.0	pF
C_{PD}	Power dissipation capacitance per buffer	V_I = GND to V_{CC}[1]	Outputs enabled	25	pF
			Outputs disabled	4	

NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; C_L = output load capacitance in pF;
   f_o = output frequency in MHz; V_{CC} = supply voltage in V; $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

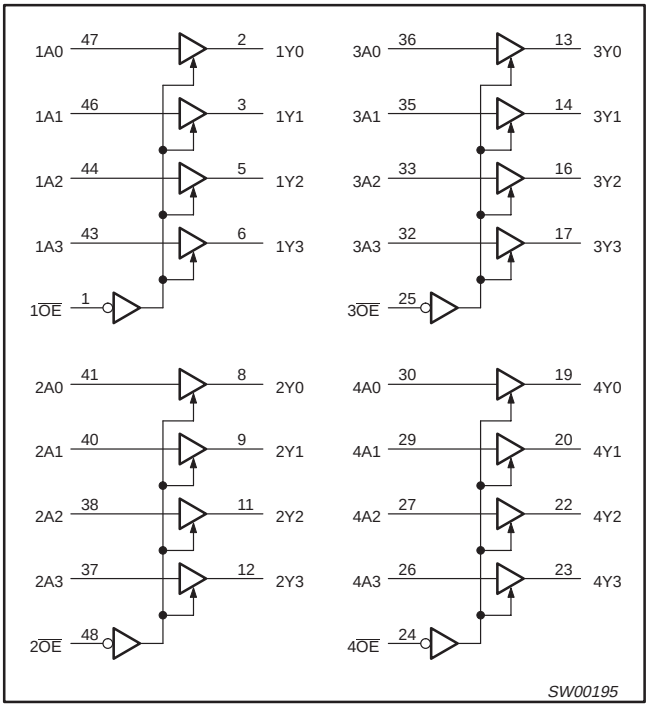
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVC16244 DL	AC16244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVC16244 DGG	AC16244 DGG	SOT362-1
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVCH16244 DL	ACH16244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVCH16244 DGG	ACH16244 DGG	SOT362-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	$1\overline{OE}$	Output enable input (active LOW)
2, 3, 5, 6	1Y0 to 1Y3	Data outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V_{CC}	Positive supply voltage
8, 9, 11, 12	2Y0 to 2Y3	Data outputs
13, 14, 16, 17	3Y0 to 3Y3	Data outputs
19, 20, 22, 23	4Y0 to 4Y3	Data outputs
24	$4\overline{OE}$	Output enable input (active LOW)
25	$3\overline{OE}$	Output enable input (active LOW)
30, 29, 27, 26	4A0 to 4A3	Data inputs
36, 35, 33, 32	3A0 to 3A3	Data inputs
41, 40, 38, 37	2A0 to 2A3	Data inputs
47, 46, 44, 43	1A0 to 1A3	Data inputs
48	$2\overline{OE}$	Output enable input (active LOW)

LOGIC SYMBOL

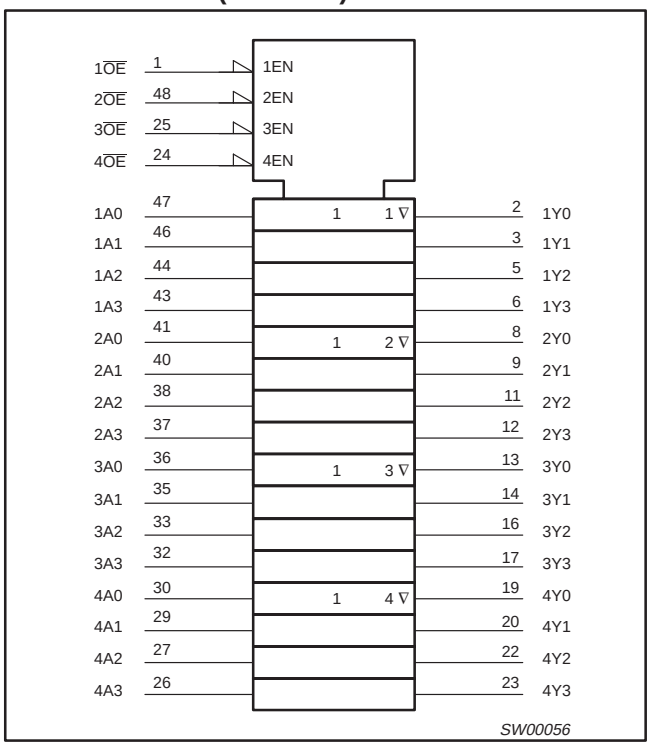


FUNCTION TABLE

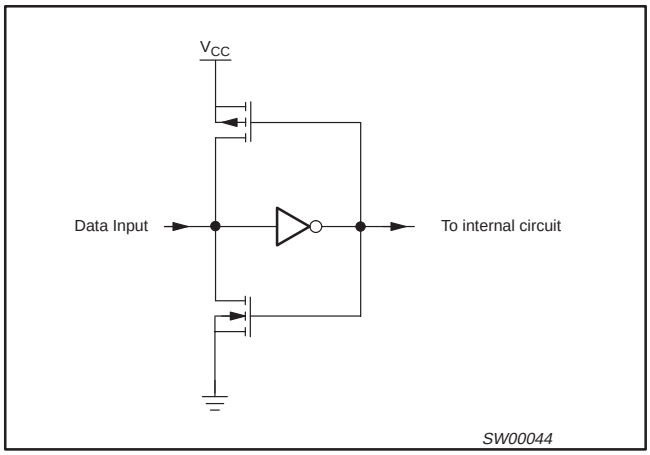
INPUTS		OUTPUT
$n\overline{OE}$	**nAn**	**nYn**
L	L	L
L	H	H
H	X	Z

H = HIGH voltage level
L = LOW voltage level
X = don't care
Z = high impedance OFF-state

LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V_{CC}	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	
	DC supply voltage (for low-voltage applications)		1.2	3.6	
V_I	DC Input voltage range	For data input pins with bus hold	0	V_{CC}	V
		For data input pins without bus hold	0	5.5	
		For control pins	0	5.5	
V_O	DC output voltage range		0	V_{CC}	V
T_{amb}	Operating free-air temperature range		–40	+85	°C
t_r, t_f	Input rise and fall times	V_{CC} = 2.3 to 3.0V V_{CC} = 3.0 to 3.6V	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS[1]

In accordance with the Absolute Maximum Rating System (IEC 134)
Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		–0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	–50	mA
V_I	DC input voltage	For data inputs with bus hold[2]	–0.5 to V_{CC} +0.5	V
		For data inputs without bus hold[2]	–0.5 to +5.5	
		For control pins[2]	–0.5 to +5.5	
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V_O	DC output voltage	Note 2	–0.5 to V_{CC} +0.5	V
I_O	DC output source or sink current	V_O = 0 to V_{CC}	±50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		±100	mA
T_{stg}	Storage temperature range		–65 to +150	°C
P_{TOT}	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: –40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	 850 600	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP[1]	MAX	
V_{IH}	HIGH level Input voltage	V_{CC} = 1.2V	V_{CC}			V
		V_{CC} = 1.8V	0.7*V_{CC}	0.9		
		V_{CC} = 2.3 to 2.7V	1.7	1.2		
		V_{CC} = 2.7 to 3.6V	2.0	1.5		
V_{IL}	LOW level Input voltage	V_{CC} = 1.2V			GND	V
		V_{CC} = 1.8V		0.9	0.2*V_{CC}	
		V_{CC} = 2.3 to 2.7V		1.2	0.7	
		V_{CC} = 2.7 to 3.6V		1.5	0.8	
V_{OH}	HIGH level output voltage	V_{CC} = 1.8 to 3.6V; V_I = V_{IH} or V_{IL}; I_O = –100µA	V_{CC}–0.2	V_{CC}		V
		V_{CC} = 1.8V; V_I = V_{IH} or V_{IL}; I_O = –6mA	V_{CC}–0.4	V_{CC}–0.10		
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = –6mA	V_{CC}–0.3	V_{CC}–0.08		
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = –12mA	V_{CC}–0.5	V_{CC}–0.17		
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = –18mA	V_{CC}–0.6	V_{CC}–0.26		
		V_{CC} = 2.7V; V_I = V_{IH} or V_{IL}; I_O = –12mA	V_{CC}–0.5	V_{CC}–0.14		
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL}; I_O = –24mA	V_{CC}–1.0	V_{CC}–0.28		
V_{OL}	LOW level output voltage	V_{CC} = 1.8 to 3.6V; V_I = V_{IH} or V_{IL}; I_O = 100µA		GND	0.20	V
		V_{CC} = 1.8V; V_I = V_{IH} or V_{IL}; I_O = 6mA		0.09	0.30	
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = 6mA		0.07	0.20	
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = 12mA		0.15	0.40	
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL}; I_O = 18mA		0.23	0.60	
		V_{CC} = 2.7V; V_I = V_{IH} or V_{IL}; I_O = 12mA		0.14	0.40	
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL}; I_O = 24mA		0.27	0.55	
I_I	Input leakage current per data pin with bus hold	V_{CC} = 1.8 to 3.6V; V_I = V_{CC} or GND		0.1	5	µA
	Input leakage current per data pin without bus hold	V_{CC} = 1.8 to 3.6V; V_I = 5.5 V or GND		0.1	5	
	Input leakage current per control pin	V_{CC} = 1.8 to 3.6V; V_I = 5.5 V or GND		0.1	5	
I_{IHZ}/I_{ILZ}	Input current for common I/O pins	V_{CC} = 1.8 to 2.7V; V_I = V_{CC} or GND		0.1	10	µA
		V_{CC} = 3.6V; V_I = V_{CC} or GND		0.1	15	
I_{OZ}	3-State output OFF-state current	V_{CC} = 1.8 to 2.7V; V_I = V_{IH} or V_{IL}; V_O = V_{CC} or GND		0.1	5	µA
		V_{CC} = 2.7 to 3.6V; V_I = V_{IH} or V_{IL}; V_O = V_{CC} or GND		0.1	10	
I_{CC}	Quiescent supply current	V_{CC} = 1.8 to 2.7V; V_I = V_{CC} or GND; I_O = 0		0.1	20	µA
		V_{CC} = 2.3 to 3.6V; V_I = V_{CC} or GND; I_O = 0		0.2	40	
ΔI_{CC}	Additional quiescent supply current given per data I/O pin with bus hold	V_{CC} = 2.7V to 3.6V; V_I = V_{CC} – 0.6V; I_O = 0		150	750	µA
	Additional quiescent supply current given per data I/O pin without bus hold			5	500	
	Additional quiescent supply current given per control pin			5	500	

DC ELECTRICAL CHARACTERISTICS (Continued)

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP[1]	MAX	
I_{BHL}[2]	Bus hold LOW sustaining current	V_{CC} = 2.3V; V_I = 0.7V	45	–		µA
		V_{CC} = 3.0V; V_I = 0.8V	75	150		
I_{BHH}[2]	Bus hold HIGH sustaining current	V_{CC} = 2.3V; V_I = 1.7V	–45			µA
		V_{CC} = 3.0V; V_I = 2.0V	–75	–175		
I_{BHLO}[2]	Bus hold LOW overdrive current	V_{CC} = 2.7V	300			µA
		V_{CC} = 3.6V	450			
I_{BHHO}[2]	Bus hold HIGH overdrive current	V_{CC} = 2.7V	–300			µA
		V_{CC} = 3.6V	–450			

NOTES:
1. All typical values are at T_{amb} = 25°C.
2. Valid for data inputs of bus hold parts.

AC CHARACTERISTICS FOR V_{CC} = 2.3V TO 2.7V RANGE AND V_{CC} < 2.3V

GND = 0V; $t_r = t_f \leq$ 2.0ns; C_L = 30pF

SYMBOL	PARAMETER	WAVEFORM	LIMITS							UNIT
			V_{CC} = 2.3 to 2.7V			V_{CC} = 1.8V			V_{CC} = 1.2V	
			MIN	TYP[1, 2]	MAX	MIN	TYP[1]	MAX	TYP[1]	
t_{PHL}/t_{PLH}	Propagation delay nAn to nYn	1, 3	1.0	1.9	3.7	1.5	2.8	5.1	5.8	ns
t_{PZH}/t_{PZL}	3-State output enable time $n\overline{OE}$ to nYn	2, 3	1.0	2.5	4.9	1.5	3.8	7.1	8.4	ns
t_{PHZ}/t_{PLZ}	3-State output disable time $n\overline{OE}$ to nYn	2, 3	1.0	2.1	4.1	1.5	3.1	3.5	5.9	ns

NOTES:
1. All typical values are measured at T_{amb} = 25°C.
2. Typical value is measured at V_{CC} = 2.5V

AC CHARACTERISTICS FOR V_{CC} = 3.0V TO 3.6V RANGE AND V_{CC} = 2.7V

GND = 0V; $t_r = t_f \leq$ 2.5ns; C_L = 50pF

SYMBOL	PARAMETER	WAVEFORM	LIMITS						UNIT
			V_{CC} = 3.3 ± 0.3V			V_{CC} = 2.7V			
			MIN	TYP[1, 2]	MAX	MIN	TYP[1]	MAX	
t_{PHL}/t_{PLH}	Propagation delay nAn to nYn	1, 3	1.0	1.9	3.0	1.0	2.1	3.6	ns
t_{PZH}/t_{PZL}	3-State output enable time $n\overline{OE}$ to nYn	2, 3	1.0	2.3	4.0	1.0	2.9	4.9	ns
t_{PHZ}/t_{PLZ}	3-State output disable time $n\overline{OE}$ to nYn	2, 3	1.0	2.7	4.1	1.0	3.0	4.5	ns

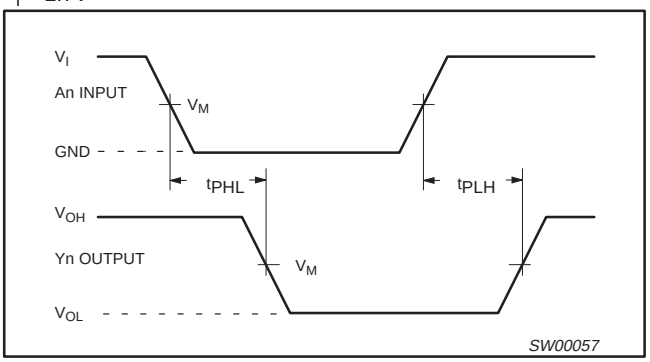
NOTES:
1. All typical values are measured at T_{amb} = 25°C.
2. Typical value is measured at V_{CC} = 3.3V

AC WAVEFORMS FOR V_{CC} = 2.3V TO 2.7V AND V_{CC} < 2.3V RANGE

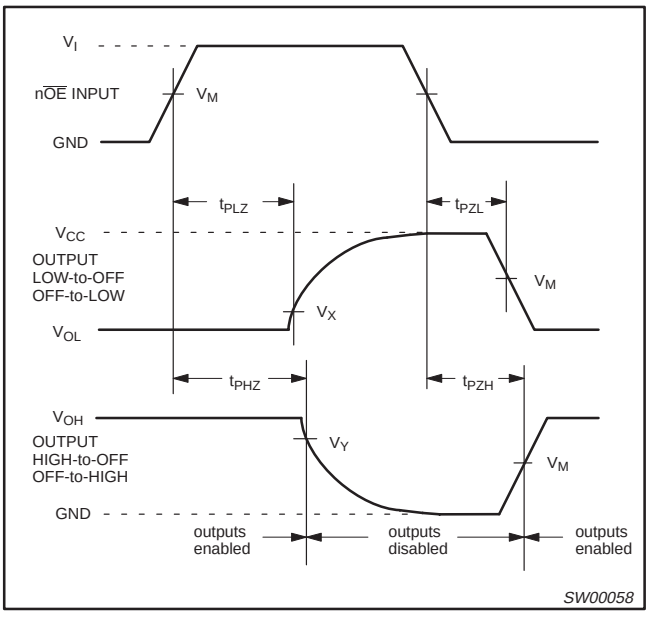
$V_M = 0.5\ V_{CC}$
$V_X = V_{OL} + 0.15V$
$V_Y = V_{OH} – 0.15V$
V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
$V_I = V_{CC}$

AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

$V_M = 1.5\ V$
$V_X = V_{OL} + 0.3V$
$V_Y = V_{OH} – 0.3V$
V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
$V_I = 2.7V$

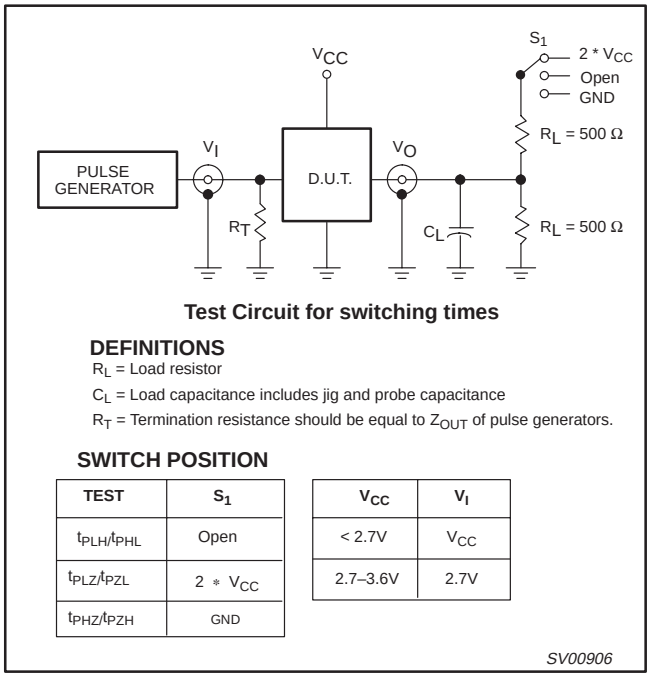


Waveform 1. Input (An) to output (Yn) propagation delay times



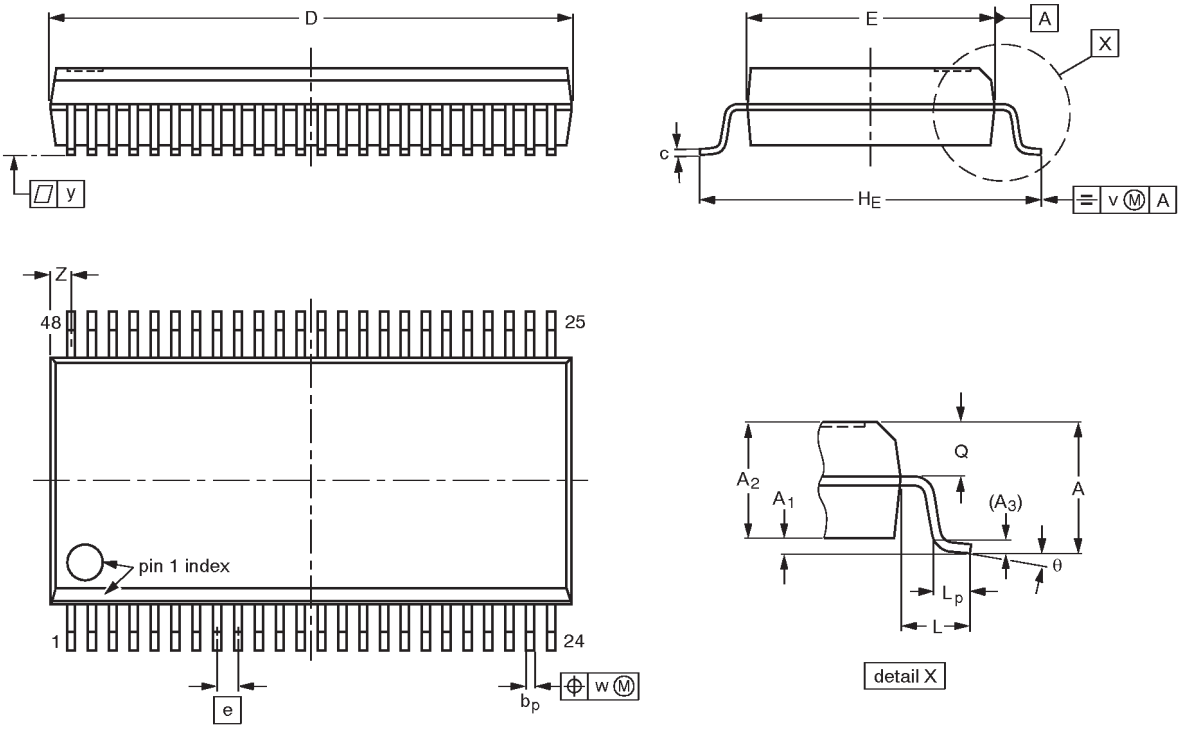
Waveform 2. 3-State enable and disable times

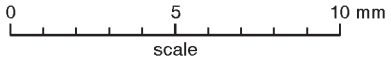
TEST CIRCUIT



Waveform 3. Load circuitry for switching times

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm **SOT370-1**





DIMENSIONS (mm are the original dimensions)

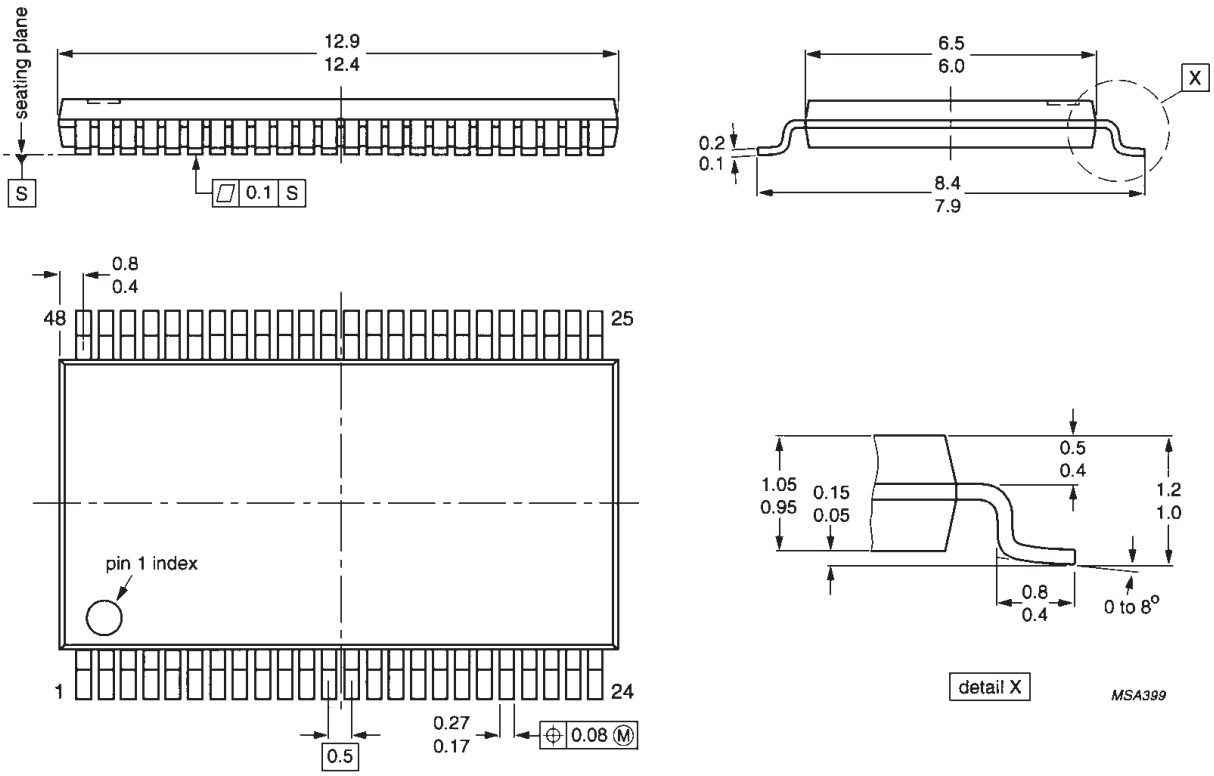
UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (1)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT370-1		MO-118AA				~~93-11-02~~ 95-02-04

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm **SOT362-1**



Dimensions in mm.

DEFINITIONS

Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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